



#### **NPN SMALL SIGNAL TRANSISTOR IN SOT23**

#### **Features**

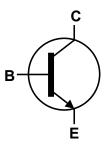
- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856 BC858
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

#### **Mechanical Data**

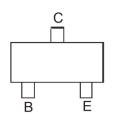
- Case: SOT23
- Case material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (Approximate)







Device Symbol



Top View Pin-Out

#### Ordering Information (Notes 4 & 5)

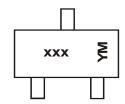
Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC846A-7-F	AEC-Q101	K1Q	7	3,000
BC846AQ-7-F	Automotive	K1Q	7	3,000
BC846B-7-F	AEC-Q101	K1R	7	3,000
BC846BQ-7-F	Automotive	K1R	7	3,000
BC846B-13-F	AEC-Q101	K1R	13	10,000
BC846BQ-13-F	Automotive	K1R	13	10,000
BC847A-7-F	AEC-Q101	K1Q	7	3,000
BC847AQ-7-F	Automotive	K1Q	7	3,000
BC847A-13-F	AEC-Q101	K1Q	13	10,000
BC847B-7-F	AEC-Q101	K1R	7	3,000
BC847BQ-7-F	Automotive	K1R	7	3,000

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC847B-13-F	AEC-Q101	K1R	13	10,000
BC847C-7-F	AEC-Q101	K1M	7	3,000
BC847CQ-7-F	Automotive	K1M	7	3,000
BC847C-13-F	AEC-Q101	K1M	13	10,000
BC848A-7-F	AEC-Q101	K1Q	7	3,000
BC848B-7-F	AEC-Q101	K1R	7	3,000
BC848B-13-F	AEC-Q101	K1R	13	10,000
BC848C-7-F	AEC-Q101	K1M	7	3,000
BC848CQ-7-F	Automotive	K1M	7	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



 $\begin{array}{l} xxx = \text{Product Type Marking Code} \\ YM = \text{Date Code Marking} \\ Y \text{ or } \overline{\underline{Y}} = \text{Year (ex: Y = 2011)} \\ M \text{ or } \overline{\underline{M}} = \text{Month (ex: 9 = September)} \\ \end{array}$ 

#### Date Code Key

Year	2010		2011	2012		2013	2014		2015	2016		2017	
Code	X		Υ	Z		Α	В		С	D		Е	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	No	v De	<b>€</b> C
Code	1	2	3	4	5	6	7	8	9	0	N		)

BC846A – BC848C Document Number: DS11108 Rev. 26 - 2



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V <sub>CBO</sub>	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V <sub>CEO</sub>	45	V
	BC848		30	
Emitter-Base Voltage	BC846, BC847	V	6.0	W
Emilier-base voltage	BC848	V <sub>EBO</sub>	5.0	V
Continuous Collector Current		Ic	100	mA
Peak Collector Current		I <sub>CM</sub>	200	mA
Peak Emitter Current		I <sub>EM</sub>	200	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	Ь	310	mW	
Power Dissipation	(Note 7)	$P_{D}$	350	11100	
Thermal Decistance, Junction to Ambient	(Note 6)	Б	403	0000	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	357	°C/W	
Thermal Resistance, Junction to Leads (Note 8)		$R_{\theta JL}$	350	°C/W	
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-65 to +150	°C		

### ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

<sup>6.</sup> For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

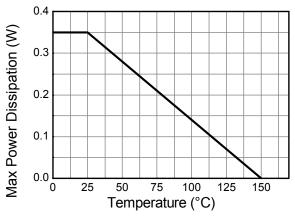
<sup>7.</sup> Same as note (6), except the device is mounted on 15 mm x 15mm 1oz copper.

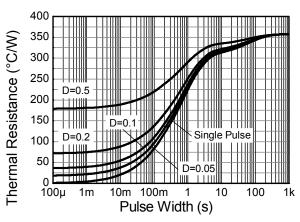
<sup>8.</sup> Thermal resistance from junction to solder-point (at the end of the leads).

<sup>9.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



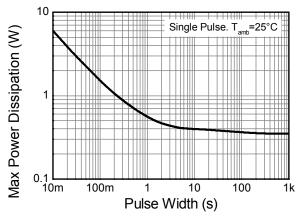
### **Thermal Characteristics and Derating Information**





**Derating Curve** 

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



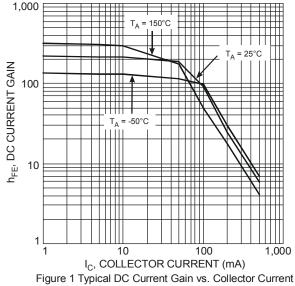
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

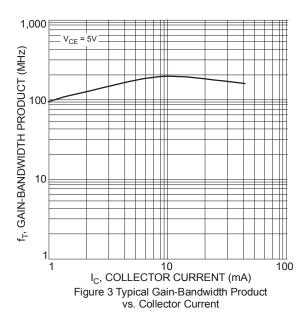
Ch	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC846		80	71	-			
Collector-Base Breakdown V	oltage	BC847	BV <sub>CBO</sub>	50	_	_	V	$I_C = 10\mu A$	
	•	BC848		30					
Callantan Fraittan Brankdayya	\/alta==	BC846		65		_	V		
Collector-Emitter Breakdown (Note 10)	voltage	BC847	$BV_CEO$	45	_			$I_C = 10mA$	
(Note 10)		BC848		30					
Emitter-Base Breakdown Vol	tago	BC846 / BC847	BV <sub>EBO</sub>	6			V	I <sub>E</sub> = 1μA	
Emilier-base Breakdown voi	lage	BC848	DA FRO	5			V	ΙΕ – ΙμΑ	
Collector Cutoff Current			I <sub>CBO</sub>	_	_	15	nA	V <sub>CB</sub> = 30V	
Concetor Caton Carrent			ICBO			5	μΑ	$V_{CB} = 30V, T_J = +150$ °C	
		BC846				15		V <sub>CE</sub> = 80V	
Collector Emitter Cutoff Curre	ent	BC847	I <sub>CES</sub>	_	_	15	nA	V <sub>CE</sub> = 50V	
		BC848				15		V <sub>CE</sub> = 30V	
Emitter Base Cutoff Current			I <sub>EBO</sub>		_	100	nA	V <sub>EB</sub> = 5V	
Carall Cianal Compant Caia	BC846A / E	C847A / BC848A			200				
Small Signal Current Gain (Note 10)	BC846B / E	C847B / BC848B	h <sub>fe</sub>	_	330	_	_		
(Note 10)	BC847	'C / BC848C	7		600			_	
Input Impedance		C847A / BC848A			2.7				
(Note 10)		C847B / BC848B	h <sub>ie</sub>	_	4.5	_	kΩ		
(14016-10)	BC847C / BC848C				8.7			$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
Output Admittance		C847A / BC848A			18			f=1.0kHz	
(Note 10)	BC846B / BC847B / BC848B		h <sub>oe</sub>		30	_	μS		
(11010-10)		C / BC848C			60				
Reverse Voltage Transfer		C847A / BC848A	1		1.5x10 <sup>-4</sup>				
Ratio (Note 10)	BC846B / BC847B / BC848B		h <sub>re</sub>	_	2x10 <sup>-4</sup>	_	_		
, ,		7C / BC848C		440	3x10 <sup>-4</sup>				
DC Compant Cain (Nata 40)		3C847A / BC848A		110	180 290	220			
DC Current Gain (Note 10)		C847B / BC848B	h <sub>FE</sub>	200		450	_	$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
0 " 1 5 " 0 1 "		C / BC848C		420	520 90	800 250		1 101 0.51	
Collector-Emitter Saturation \( \text{(Note 10)} \)	voltage		V <sub>CE(sat)</sub>	_			mV	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0.5mA	
(Note 10)			- ( ,		200	600		I <sub>C</sub> = 100mA, I <sub>B</sub> = 5.0mA	
Base-Emitter Turn-On Voltage	e(Note 10)		V <sub>BE(on)</sub>	580	660	700	mV	$I_C = 2mA$ , $V_{CE} = 5V$	
	, ((1000 10)		• BE(OII)	_	_	770		$I_C$ = 10mA, $V_{CE}$ = 5V	
Base-Emitter Saturation Voltage(Note 10)		V <sub>BE(sat)</sub>	_	700	_	mV	$I_C = 10mA, I_B = 0.5mA$		
		` ′		900		111.4	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$		
Output Capacitance		$C_{obo}$	_	3	_	pF	V <sub>CB</sub> = 10V, f = 1.0MHz		
Transition Frequency		f <sub>T</sub>	100	300	_	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA, f = 100MHz		
Noise Figure			NF	_	2	10	dB	$V_{CE}$ =5V, $I_{C}$ =200μA $R_{S}$ =2k $\Omega$ , f=1kHz $\Delta$ f=200Hz	

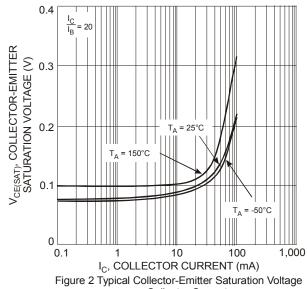
Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%



# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





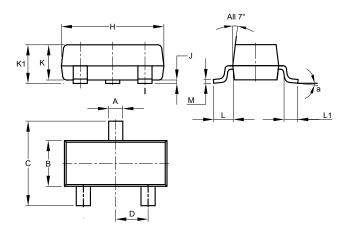


vs. Collector Current



### **Package Outline Dimensions**

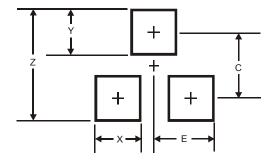
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	8°							
All	All Dimensions in mm							

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35



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